



MMST5401

160V PNP SMALL SIGNAL TRANSISTOR IN SOT323

Features

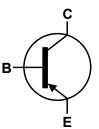
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary PNP Type: MMST5551
- Ideal for Low Power Amplification and Switching
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

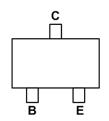
- Case: SOT323
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>@3
- · Weight: 0.006 grams (approximate)







Device Symbol



Top View Pin-Out

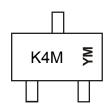
Ordering Information (Notes 4 & 5)

Device	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per reel
MMST5401-7-F	AEC-Q101	K4M	7	8	3,000
MMST5401-13-F	AEC-Q101	K4M	13	8	10,000
MMST5401Q-7-F	Automotive	K4M	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K4M = Product Type Marking Code YM = Date Code Marking Y or \underline{Y} = Year (ex: A = 2013) M or \underline{M} = Month (ex: 9 = September)

Date Code Key

Year	2010		2011	2012		2013	2014		2015	2016		2017
Code	X		Υ	Z		Α	В		С	D		E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-160	V
Collector-Emitter Voltage	V _{CEO}	-150	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Continuous Collector Current	Ic	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	P _D	200	mW
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)						
Collector-Base Breakdown Voltage	V_{CBO}	-160	_	V	$I_C = -100 \mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage	V _{CEO}	-150	_	V	$I_C = -1.0 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage	V_{EBO}	-5.0	_	V	$I_E = -10\mu A, I_C = 0$	
Collector Cutoff Current	lana		-50	nA	V _{CB} = -120V, I _E = 0	
Collector Guton Gurrent	I _{CBO}		-30	μA	$V_{CB} = -120V, I_E = 0, T_A = +100$ °C	
Emitter Cutoff Current	I _{EBO}	_	-50	nA	$V_{EB} = -3.0V, I_{C} = 0$	
ON CHARACTERISTICS (Note 8)						
DC Current Gain	h _{FE}	50 60 50	240 —	_	$I_C = -1.0 \text{mA}$, $V_{CE} = -5.0 \text{V}$ $I_C = -10 \text{mA}$, $V_{CE} = -5.0 \text{V}$ $I_C = -50 \text{mA}$, $V_{CE} = -5.0 \text{V}$	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.2 -0.5	٧	$I_{C} = -10\text{mA}, I_{B} = -1.0\text{mA}$ $I_{C} = -50\text{mA}, I_{B} = -5.0\text{mA}$	
Base-Emitter Saturation Voltage	V _{BE(SAT)}		-1.0	V	$I_C = -10$ mA, $I_B = -1.0$ mA $I_C = -50$ mA, $I_B = -5.0$ mA	
SMALL SIGNAL CHARACTERISTICS			-			
Output Capacitance	C_{obo}		6.0	pF	$V_{CB} = -10V$, $f = 1.0MHz$, $I_E = 0$	
Small Signal Current Gain	h _{fe}	40	200	_	$V_{CE} = -10V, I_{C} = -1.0mA,$ f = 1.0kHz	
Current Gain-Bandwidth Product	f⊤	100	300	MHz	$V_{CE} = -10V, I_{C} = -10mA,$ f = 100MHz	
Noise Figure	NF		8.0	dB	V_{CE} = -5.0V, I_{C} = -200 μ A, R _S =10 Ω , f = 1.0kHz	

Notes:

^{6.} For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.
8. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

= -50°C

100

10

1,000

100



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

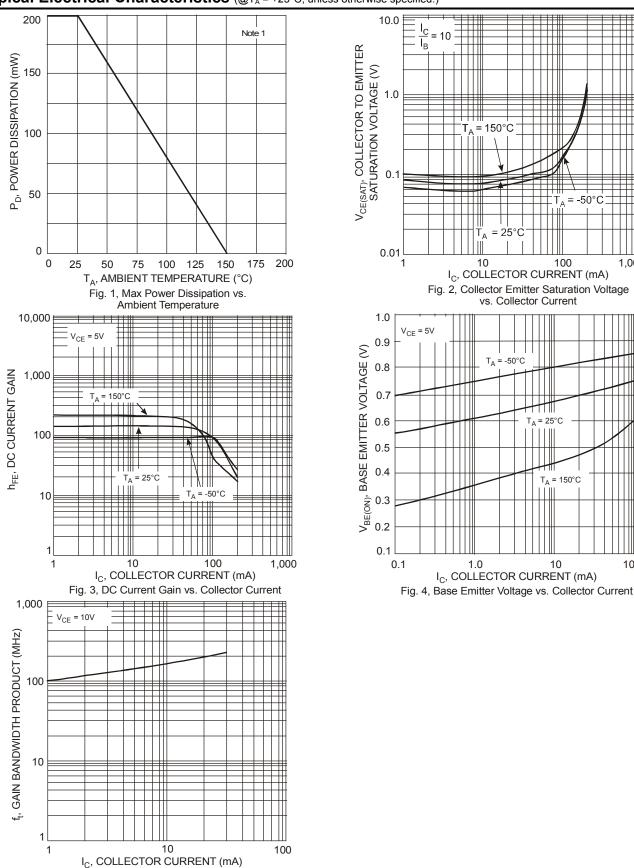
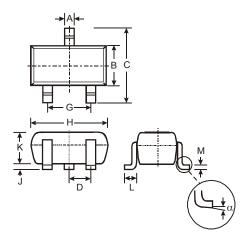


Fig. 5, Gain Bandwidth Product vs. Collector Current



Package Outline Dimensions

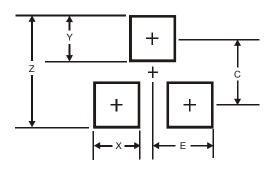
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT323						
Dim	Min	Max	Тур			
Α	0.25	0.40	0.30			
В	1.15	1.35	1.30			
С	2.00	2.20	2.10			
D	-	-	0.65			
G	1.20	1.40	1.30			
Η	1.80	2.20	2.15			
J	0.0	0.10	0.05			
K	0.90	1.00	1.00			
٦	0.25	0.40	0.30			
М	0.10	0.18	0.11			
α	0°	8°	-			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Υ	0.9
С	1.9
Е	1.0

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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